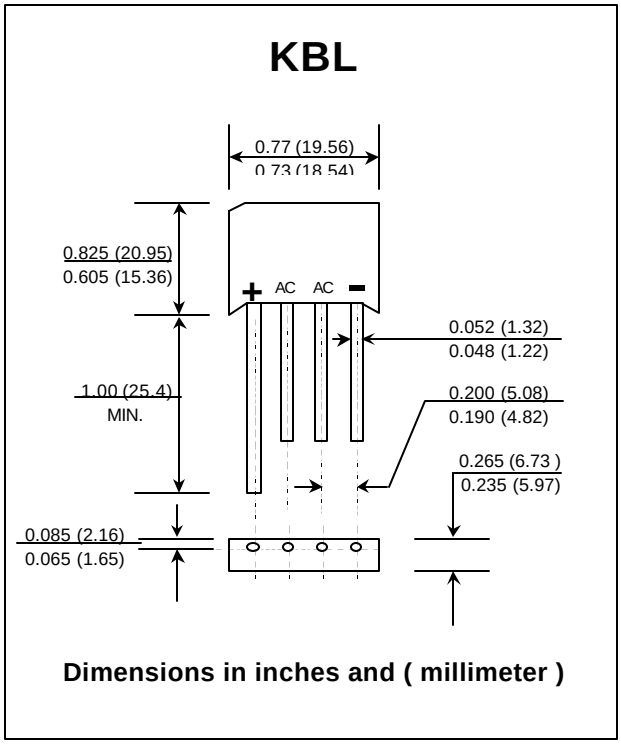
KBL400 - KBL410

SILICON BRIDGE RECTIFIERS

PRV : 50 - 1000 Volts
Io : 4.0 Amperes



FEATURES :

* High current capability
* High surge current capability
* High reliability
* Low reverse current
* Low forward voltage drop
* Ideal for printed circuit board

MECHANICAL DATA :

* Case : Molded plastic
* Epoxy : UL94V-O rate flame retardant
* Terminals : Plated lead solderable per MIL-STD-202, Method 208 guaranteed
* Polarity : Polarity symbols marked on case
* Mounting position : Any
* Weight : 5.15 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

RATING	SYMBOL	KBL 400	KBL 401	KBL 402	KBL 404	KBL 406	KBL 408	KBL 410	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Current Tc=50°C	$I_{F(AV)}$	4.0							Amps.
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	200							Amps.
Rating for fusing (t < 8.3 ms.)	I^2t	166							A^2S
Maximum Forward Voltage per Diode at I_F = 4 Amps.	V_F	1.1							Volts
Maximum DC Reverse Current Ta = 25 °C	I_R	10							µA
at Rated DC Blocking Voltage Ta = 100 °C	$I_{R(H)}$	1.0							mA
Typical Thermal Resistance (Note 1)	RθJA	10							°C/W
Operating Junction Temperature Range	T_J	- 50 to + 150							°C
Storage Temperature Range	T_{STG}	- 50 to + 150							°C

Notes :

1) Thermal resistance from Junction to Ambient with units mounted on a 3" X 3" X 0.11" THK (7.5cm X 7.5cm X 0.3cm) Cu. plate.

UPDATE : APRIL 23,1998

RATING AND CHARACTERISTIC CURVES (KBL400 - KBL410)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

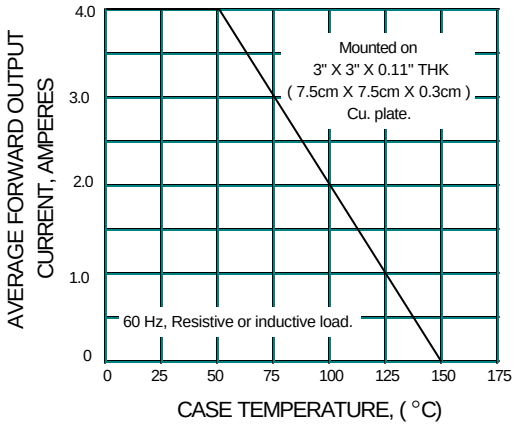


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

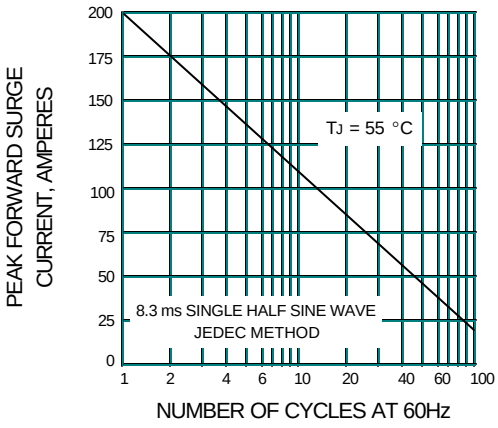


FIG.3 - TYPICAL FORWARD CHARACTERISTICS PER DIODE

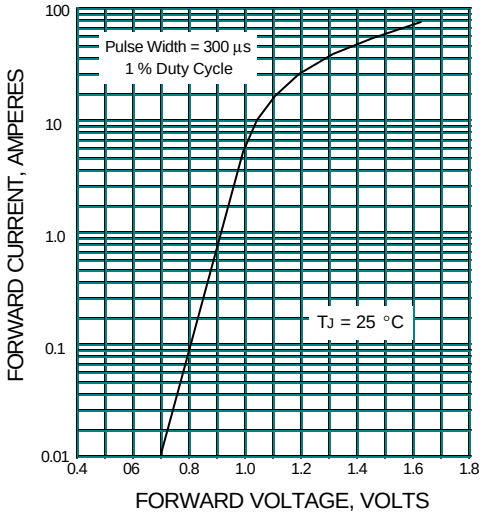


FIG.4 - TYPICAL REVERSE CHARACTERISTICS